

6-Unit 320mA Transistor Array

IR2C23/IR2C23N

T-52-07

IR2C23/IR2C23N 6-Unit 320mA Transistor Array

■ Description

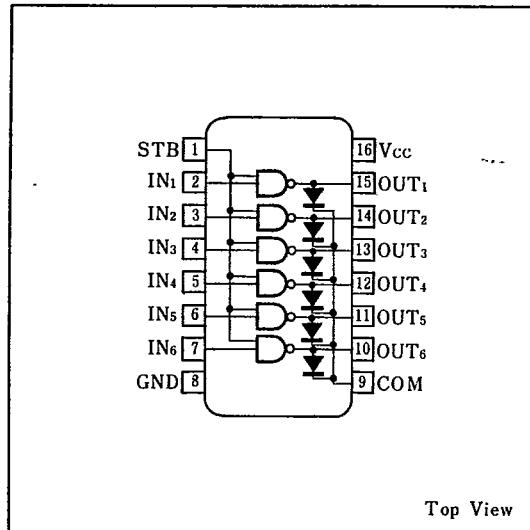
The IR2C23/IR2C23N is a 6-circuit driver IC which can be used for driving printer, relays, LEDs and lamps. The strobe pin enables all circuits to cut off without external transistors.

Clamping diodes protect output transistors from counter electromotive force.

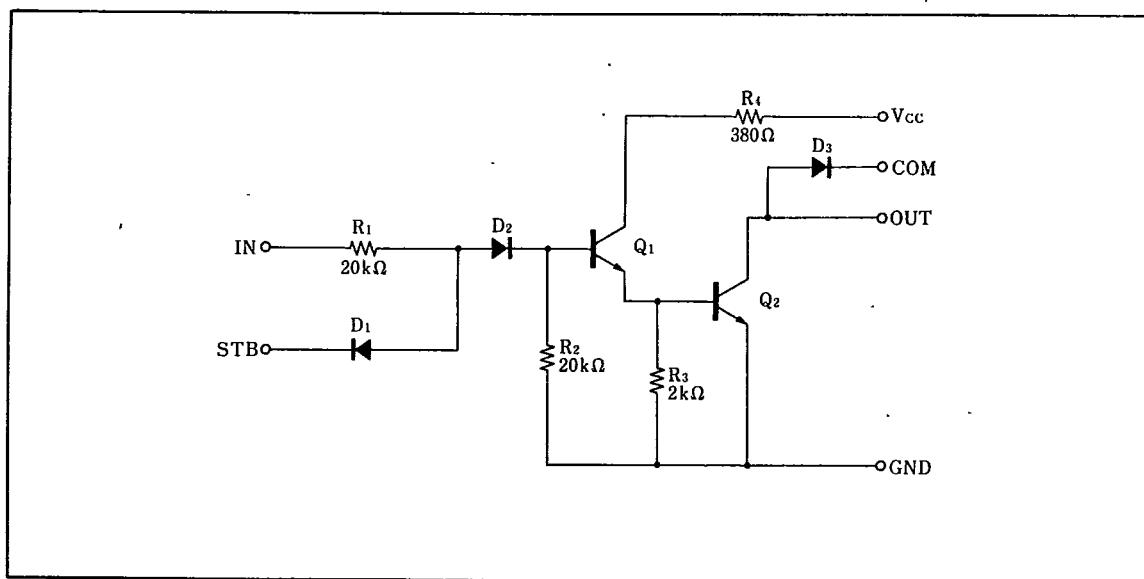
■ Features

1. With strobe pin
2. With clamping diodes
3. Output breakdown voltage
 $BV_{CEO}=20V(\text{MAX.})$
4. Output current 320mA(MAX.)
5. 16-pin dual-in-line package(IR2C23)
16-pin small-outline package(IR2C23N)

■ Pin Connections



■ Equivalent Circuit



6-Unit-320mA Transistor Array

IR2C23/IR2C23N

T-52-07

Absolute Maximum Ratings

Parameter	Symbol	Condition		Rating	Unit
Supply voltage	V _{CC}			10	V
Input voltage	V _{IN}			-25 ~ +20	V
Output current	I _{OUT}	Each circuit		320	mA
Output breakdown voltage	BV _{CCEO}			20	V
Strobe input voltage	V _{IN STB}			20	V
Clamp diode reverse voltage	V _R	For clamp diode		20	V
Clamp diode surge current	I _{surge}	For clamp diode		320	mA
Power dissipation	P _D	T _a ≤ 25°C	IR2C23	1,470	mW
			IR2C23N	600	
P _D derating ratio	ΔP _D /°C	T _a > 25°C	IR2C23	14.7	mW/°C
			IR2C23N	6	
Operating temperature	T _{opr}			-20 ~ +75	°C
Storage temperature	T _{stg}			-55 ~ +150	°C

**Recommend Operating Conditions**

(Ta = -20 ~ +75°C)

Parameter	Symbol	Condition		MIN.	TYP.	MAX.	Unit
Supply voltage	V _{CC}			3		8	V
Max. output voltage	V _{CCEO}					20	V
Output current	I _{OUT}	V _{CC} =6.5V, at 25% duty or less				300	mA
		V _{CC} =6.5V, at 65% duty or less				150	
Input "High" voltage	V _{IH}	I _{OUT} =150mA		5			V
		I _{OUT} =300mA		7			
Input "Low" voltage	V _{IL}	I _{OUT} (Leak)=50 μA				1	V
Strobe input "High" voltage	V _{IH STB}	For strobe pin		2.4			V
Strobe input "Low" voltage	V _{IL STB}	For strobe pin	IR2C23			0.4	V
			IR2C23N			0.2	

Electrical Characteristics(V_{CC}=8V, Ta = -20 ~ +75°C)

Parameter	Symbol	Condition		MIN.	TYP.	MAX.	Unit
Output voltage	V _{CCEO}	V _{IN} =18V, V _{IN STB} =0.2V, I _{OUT} =100 μA				20	V
On state output voltage	V _{OUT ON₁}	V _{IN} =7V V _{IN STB} =2.4V	V _{CC} =6.5V, I _{OUT} =300mA		0.6	1.0	V
			V _{CC} =6.5V, I _{OUT} =250mA		0.5	0.85	
			V _{CC} =3V, I _{OUT} =120mA		0.3	0.5	
Input current	I _{IN}	V _{IN} =18V, V _{IN STB} =2.4V			0.8	1.8	mA
Input reverse leakage current	I _{IR}	V _{IN} =-25V				-20	μA
Strobe input current	I _{IN STB}	For strobe pin, V _{IN} =18V(All input), V _{IN STB} =0.2V		-4			mA
Strobe input reverse leakage current	I _{IR STB}	For strobe pin, V _{IN} =0V, V _{IN STB} =20V				20	μA
Clamp diode forward voltage	V _F	For clamp diode, I _{FM} =320mA			1.4	2.4	V
Clamp diode reverse voltage	V _R	For clamp diode, I _R =100 μA		20			V
Supply current	I _{CC}	V _{IN} =7V(All input), V _{IN STB} =2.4V				200	mA
DC current amplitude	h _{FE}	V _{CC} =6.5V, V _{CCEO} =4V, I _{OUT} =300mA, Ta=25°C		1,000			